FUJITSU SEMICONDUCTOR DATA SHEET

DS04-27209-1E

ASSP

SWITCHING REGULATOR CONTROLLER

MB3788

DESCRIPTION

The MB3788 is a dual-channel PWM-type switching regulator controller; it incorporates a reference voltage.

The MB3788 has a PWM circuit and an output circuit as well as a reference voltage power supply with a voltage accuracy of $\pm 1\%$. The maximum operating frequency is 1 MHz. It is designed for a voltage-drop output switching regulator suitable for a logic power supply or speed control of a DC motor. The MB3788 is compatible with all master ICs producing triangular waves, saw-

The MB3788 is compatible with all master ICs producing triangular waves, sawtooth waves and sine waves with an amplitude of 1.3 to 1.9 V.

It can be used in high-performance portable equipment such as a video camcorder or notebook personal computer (word processor).

■ FEATURES

- Wide operating power supply voltage range: 3.6 to 18 V
- Low power dissipation
- Operating: 1.9 mA (standard)
 - Standby: 10 µA max.
- High-frequency operation: 100 kHz to 1 MHz
- On-chip timer and latch-type short-circuit detection circuit
- Wide error amplifier input voltage range: -0.2 V to Vcc 1.8 V
- On-chip high-accuracy reference voltage circuit: 2.50 V ±1%
- Output circuit
 - PNP transistor drive output pin: Push-pull type
 - ON/OFF current values set independently
- On-chip standby function and output control function
- High-density packaging: SSOP-24P

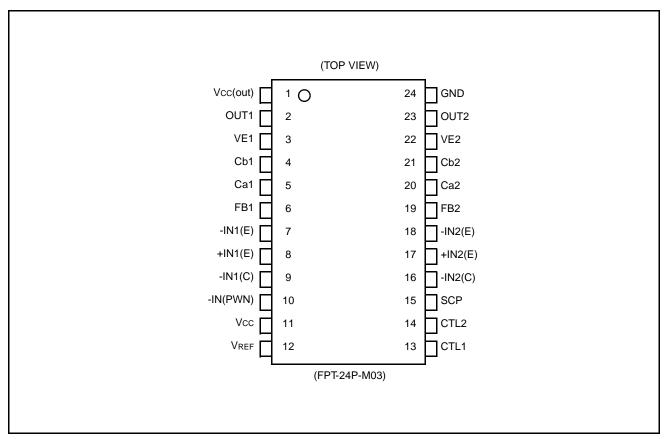




This device contains circuitry to protect the inputs against damage due to high static voltages or electric fields. However, it is advised that normal precautions be taken to avoid application of any voltage higher than maximum rated voltages to this high impedance circuit.



■ PIN ASSIGNMENT



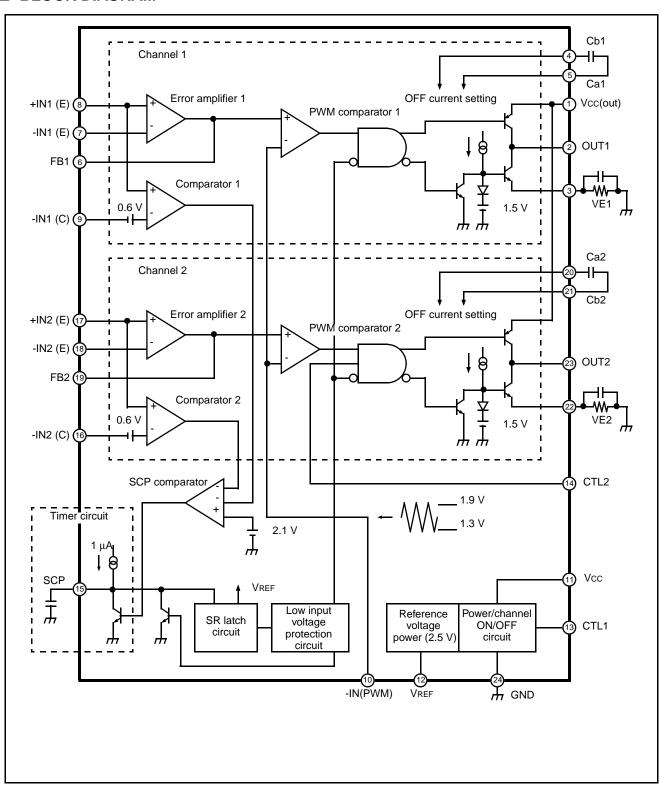
■ PIN DESCRIPTION

Pin No.		Pin name	I/O	Descriptions			
	2	OUT1	0	Channel 1 push-pull type output			
	3	VE1	I	Channel 1 output current setting			
	4	Ca1	_	Channel 1 output transistor OFF current setting: Output transistor OFF			
Channel	5	Cb1	_	The current is set by connecting a capacitor between pins Ca1 and Cb1.			
1	6	FB1	0	Channel 1 error amplifier output			
	7	-IN1(E)	I	Channel 1 error amplifier inversion input			
	8	+IN1(E)		Channel 1 error amplifier non-inversion input			
	9	-IN1(C)	I	Channel 1 comparator inversion input			
	16	-IN2(C)	I	Channel 2 comparator inversion input			
	17	+IN2(E)	I	Channel 2 error amplifier non-inversion input			
	18	-IN2(E)	I	Channel 2 error amplifier inversion input			
Channel	19	FB2	0	Channel 2 error amplifier output			
2	20	Ca2	_	Channel 2 output transistor OFF current setting: Output transistor OFF			
	21	Cb2	_	The current is set by connecting a capacitor between pins Ca2 and Cb2.			
	22	VE2	I	Channel 2 output current setting			
	23	OUT2	0	Channel 2 push-pull type output			
	13	CTL1	I	Power and channel 1 control pin H level: Power and channel 1 operating L level: Standby			
Control circuit	14	CTL2	I	Channel 2 control pin When CTL1 pin = H level, H level: Channel 2 operating L level: Channel 2 OFF			
	15	SCP	_	Short-circuit protection circuit capacitor connection			
	1	Vcc ²	_	Output circuit power pin			
	10	-IN(PWM)	I	Master oscillating waveform input			
Power circuit	11	VCC1	_	Reference power and control circuit power			
	12	VREF	0	Reference voltage output			
	24	GND	_	Ground			

Note: The alphabetic characters in parenthesis above indicate the following input pins.

(C): Comparator(E): Error amplifier

■ BLOCK DIAGRAM



■ FUNCTIONAL DESCRIPTION

1. Major Functions

(1) Reference voltage power circuit

The reference voltage power supply produces a reference voltage (\approx 2.50 V) which is temperature-compensated by the voltage supplied from the power pin (pin 11); it is used as the IC internal circuit operating power supply. The reference voltage can also be output externally at 1 mA from VREF pin (pin12).

(2) Error amplifier

The error amplifier detects the switching regulator output voltage and outputs a PWM control signal. It has a wide in-phase input voltage range of -0.2 V to Vcc - 1.8 V to make setting from an external power supply easy.

Connecting the output pin and inversion input pin of the error amplifier through a feedback resistor and capacitor allows setting of any loop gain to provide stable phase compensation.

(3) PWM comparator

The PWM comparator controls the output pulse ON time according to the input voltage.

The voltage input to the -IN pin (PWM) turns the output transistor on when it is lower than the output voltage of the error amplifier.

(4) Output circuit

The output circuit is configured in a push-pull form and uses a PNP transistor drive system to drive a transistor of up to 30 mA. (See *How to Set Output Current*.)

2. Channel Control Function

Channels can be set ON/OFF by combining the voltage levels at pin CTL1 (pin 13) and pin CTL2 (pin 14).

Channel ON/OFF Setting Conditions

Voltage lev	el at CTL pin	Channel ON/OFF status				
CTL1	CTL2	Power circuit	Channel			
L	×	Stand by state*				
Н	Н	ON		ON		
	L			OFF		

^{*}The power current in the standby state is 10 µA max.

3. Protection Functions

(1) Timer and latch-type short-circuit protection circuit

The SCP comparator detects the output voltage levels of two comparators to detect an output short circuit. If the output voltage of one comparator increases to 2.1 V, the transistor of the timer circuit is turned off and the short circuit protection capacitor connected externally to the SCP pin (pin 15) starts charging.

The latch circuit turns off the output transistor and simultaneously clears the duty cycle to 0 when the output voltage level of the comparator does not return to the normal voltage level until the capacitor voltage rises to the base-emitter junction voltage VBE (≈ 0.65 V) of the transistor. (See *How to Set Time Constant for Timer & Latch-Type Short-Circuit Protection Circuit.*)

When the protection circuit operates, recycle the power to reset the circuit.

(2) Low input voltage malfunction fail-safe circuit

A transient at power-on, or an instantaneous supply voltage drop can cause a control IC malfunction, which may damage the system. The low input voltage malfunction fail-safe circuit detects the internal reference voltage level based on the supply voltage level, resets the latch circuit, turns off the output transistor, clears the duty cycle to 0 and holds the SCP pin (pin 15) at Low level. All circuits are recovered when the supply voltage is greater than the threshold voltage of the fail-safe circuit.

■ ABSOLUTE MAXIMUM RATINGS

 $(TA = +25^{\circ}C)$

Parameter	Symbol	Conditions	Ratings	Unit
Supply voltage	Vcc	_	20	V
Control input voltage	VICTL	_	20	V
Allowable loss	PD	Ta ≤ +25°C	500*	mW
Operating ambient temperature	Тор	_	-30 to +85	°C
Storage temprature	Tstg	_	-55 to +125	°C

 $^{^{\}mbox{\scriptsize \star}}$ Value obtained when mounted on 4 cm \times 4 cm double-sided epoxy substrate

■ RECOMMENDED OPERATING CONDITIONS

 $(TA = +25^{\circ}C)$

Parameter	Symbol	Conditions		Unit		
Parameter	Symbol	Conditions	Min.	Typical	Max.	Offic
Supply voltage	Vcc	_	3.6	6.0	18	V
Reference voltage output curren	lor		-1	_	0	mA
Error amplifier input voltage	Vı		-0.2	_	Vcc - 1.8	V
Error amplifier input voltage	Vı		-0.2	_	Vcc	V
Control input voltage	VICTL		-0.2	_	18	V
Output current	lo		3.0	_	30	mA
Operating frequency	fosc		100	300	1000	kHz
Operating ambient temperature	Тор	_	-30	25	85	°C

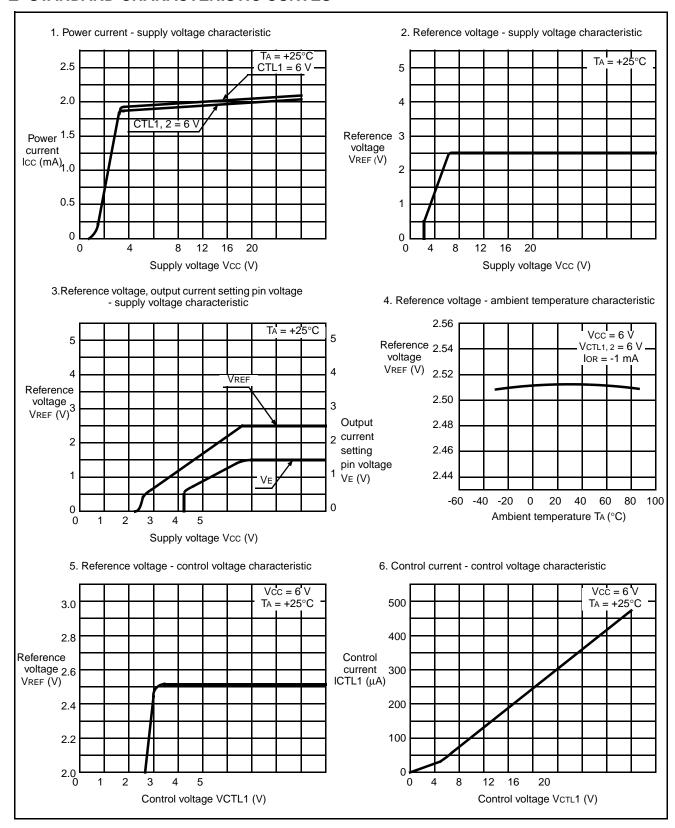
■ ELECTICAL CHARACTERISTICS

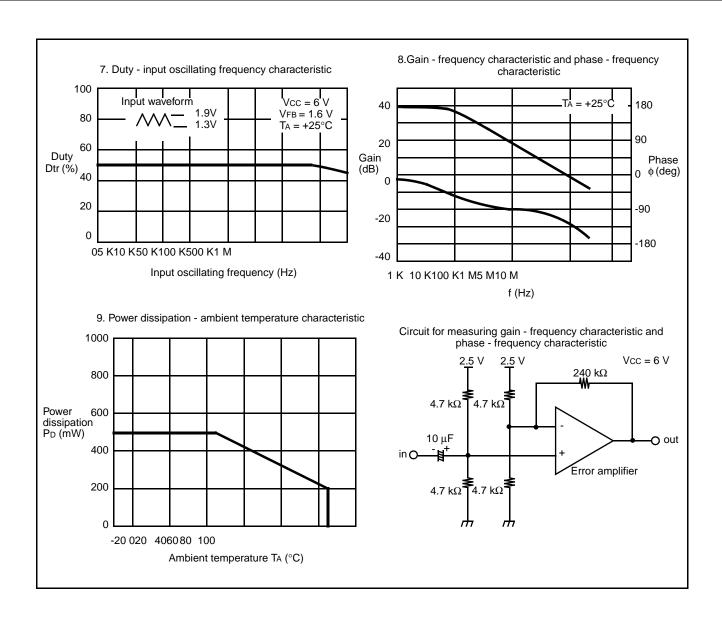
 $(VCC = 6V, TA = +25^{\circ}C)$

	Parameter		Conditions	Value			Unit
	Parameter	Symbol	Conditions	Min.	Typical	Max.	Unit
Reference voltage	Reference voltage	VREF	IOR = -1 mA	2.475	2.500	2.525	V
	Output voltage temperature variation	ΔVREF/ VREF	TA = -30° to +85°C	-2	±0.2	2	%
	Input stability	Line	Vcc = 3.6 V to 18 V	_	2	10	mV
	Load stability	Load	IOR = -0.1 mA to 1 mA	_	3	10	mV
	Short-circuit output current	los	VREF = 2 V	-20	-8	-3	mA
	Threshold voltage	VtH	_	_	2.65	_	V
Low voltage malfunction	Tilleshold voltage	VtL	_	_	2.45	_	V
fail-safe circuit	Hysteresis width	VHYS	_	80	200	_	mV
onoun	Reset voltage	VR	_	1.5	1.9	_	V
Short-circuit	Input offset voltage	Vio	_	0.58	0.65	0.72	V
detection	Input bias current	lв	VI = 0 V	-200	-100	_	nA
comparator	In-phase input voltage range	VICM	_	-0.2	_	· Vcc-1.8	V
	Threshold voltage	VtPC	_	0.60	0.65	0.70	V
Short-circuit	Input standby voltage	VSTB	_	_	50	100	mV
detector	Input latch voltage	Vı	_	_	50	100	mV
	Input source current	Ilbpc	_	-1.4	-1.0	All Max. 2.525 2 10 10 10 -3 - 0.72 - Vcc-1.8 0.70 100 -0.6 10 100 -Vcc-1.8 - - - - - - - - - - - - -	μΑ
	Input offset voltage	Vio	VFB = 1.6 V	-10	_	10	mV
	Input offset current	lio	VFB = 1.6 V	-100	_	100	nA
	Input bias current	Ів	VFB = 1.6 V	-200	-60	_	nA
	In-phase input voltage range	VICM	_	-0.2	_	Vcc-1.8	V
	Voltage gain	Av	_	60	100	_	dB
Error amplifier	Frequency bandwidth	BW	AV = 0 dB	_	800	_	kHz
	In-phase signal rejection ratio	CMRR	_	60	80	_	dB
	Maximum output voltage width	Vom+	_	VREF-0.3	2.4	_	V
	waxiinuin output voitage width	Voм-	_	_	0.05	0.5	V
	Output sink current	Іом+	VFB = 1.6 V	_	120	_	μΑ
	Output source current	Іом-	VFB = 1.6 V	_	-2	_	mA

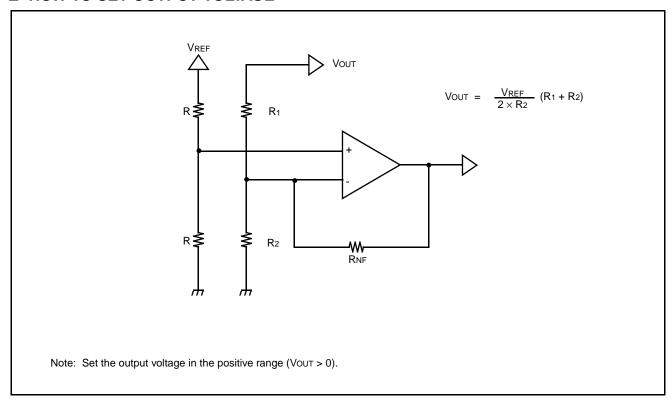
				Values			Unit
	Parameter	Symbol	Conditions	Min.	Typical	Max.	Oiiii
	Threshold voltage	Vt0	Duty cycle = 0 %	1.05	1.3	_	V
	Threshold voltage	Vt100	Duty cycle = 100 %	_	1.9	2.25	V
PWM comparator	Input sink current	IIM+	_	_	120	_	μΑ
·	Input source current	IIM-	_	_	-2	_	mA
	Input bias current	Iв	VI = 0 V	-1.0	-0.5	_	μΑ
	Threshold voltage	Vth	_	0.7	1.4	2.1	V
Control	Input current	IIН	VCTL = 5 V	_	100	200	μА
	input current	lıL	VCTL = 0 V	-10	1.3 — 1.9 2.25 120 — -2 — -0.5 — 1.4 2.1	μΑ	
	Source current	lo	_	_	-40	_	mA
Output	Sink curren	lo	R _B = 50 Ω	18	30	42	mA
	Output leak current	ILO	Vo = 18 V	_	_	20	μΑ
All devices	Standby current	Icco	_	_	0	10	μΑ
/ III GEVICES	Power current at output OFF	Icc	_	_	1.9	2.7	mA

■ STANDARD CHARACTERISTIC CURVES





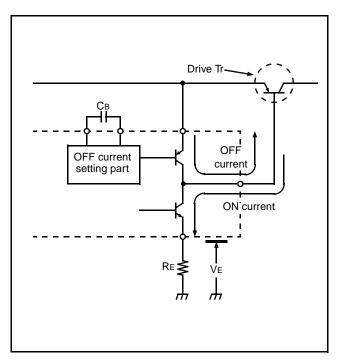
■ HOW TO SET OUTPUT VOLTAGE



■ HOW TO SET OUTPUT CURRENT

The output circuit is configured in a push-pull type as shown in Figure 1. The ON current value of the output current waveform shown in Figure 2 is a constant current and the OFF value set by RE is set by a time constant. Each output current can be calculated from the following expression:

- ON current = 1.5/Re (A) (Output current setting pin voltage: $VE \approx 1.5 \text{ V}$)
- \bullet The OFF current time constant is proportional to the value of $C_{\text{B}}.$



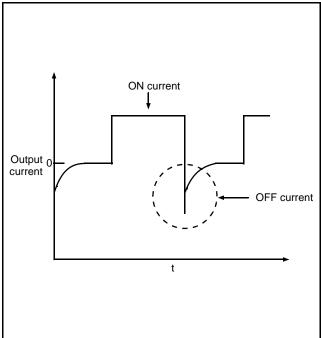
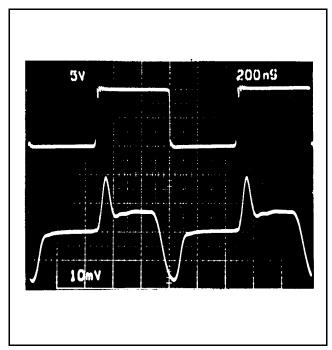


Fig.1 Output Circuit Diagram

Fig.2 Output Current Waveform





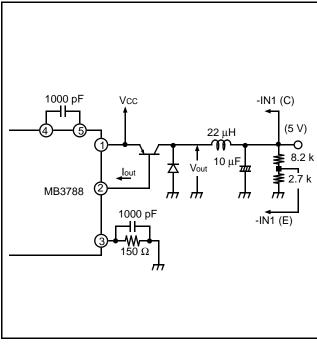


Fig.4 Measurement Circuit Diagram

■ HOW TO SET TIME CONSTANT FOR TIMER & LATCH-TYPE SHORT-CIRCUIT PROTECTION CIRCUIT

If the load conditions of the switching regulator are stable, the outputs of comparators 1 and 2 do not change, so the SP comparator outputs a High level. At this time, the SCP pin (pin 15) is held at about 50 mV.

If the load conditions change suddenly due to a load short-circuit, for example, the output voltage of the comparator of the channel becomes a High-level signal (more than 2.1 V). Then, the SVP comparator outputs a Low level and transistor Q1 is turned off. The short-circuit protection capacitor CPE externally connected to the SCP pin starts to charge.

```
VPE = 50 \text{ mV} + \text{tpe} \times 10^{-6}/\text{Cpe}

0.65 = 50 \text{ mV} + \text{tpe} \times 10^{-6}/\text{Cpe}

CPE = \text{tpe} / 0.6 \text{ (s)}
```

Once the capacitor C_{PE} is charged to about 0.65 V, the SR latch is set and the output drive transistor is turned off. At this time, the duty cycle is made low and the output voltage of the SCP pin (pin 15) is held at Low level. This closes the SR latch input to discharge CPE.

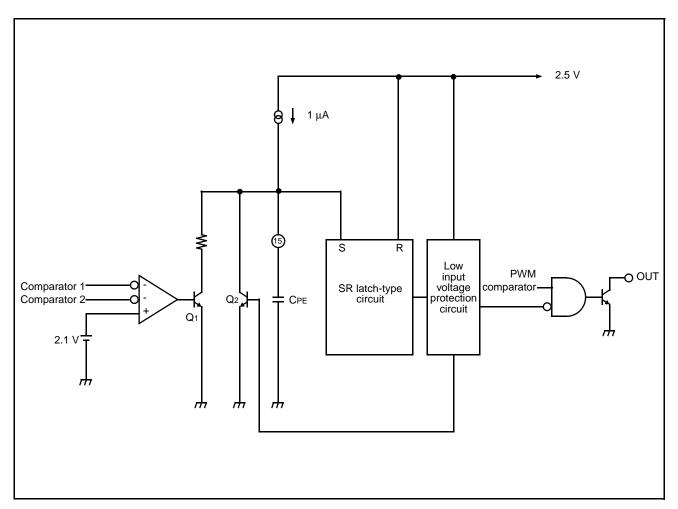


Fig. 5 Latch-Type Short-Circuit Protection Circuit

■ PROCESSING WITHOUT USING SCP PIN

If the timer and latch-type short-circuit protection circuit is not used, connect the SCP pin (pin 15) to GND as close as possible. Also, connect the input pin of each channel comparator to the Vcc pin (pin 11).

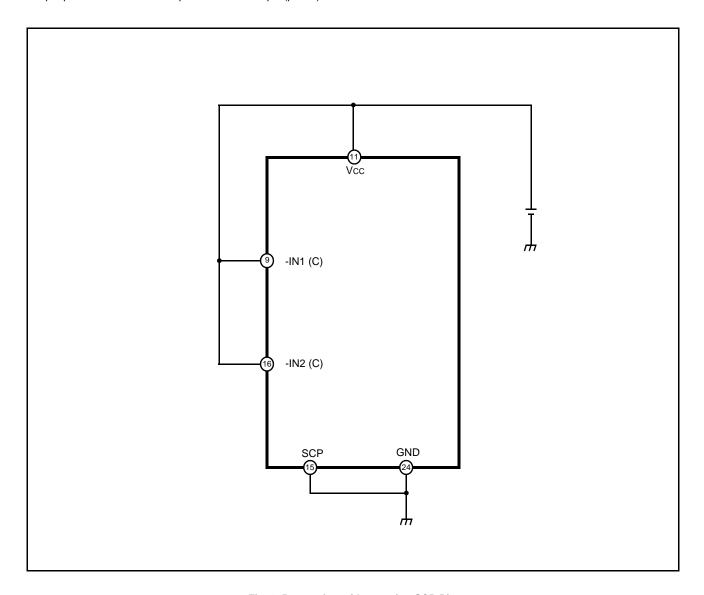


Fig. 6 Processing without using SCP Pin

■ EQUIVALENT SERIES RESISTANCE OF SMOOTHING CAPACITOR AND STABILITY OF DC/DC CONVERTER

The equivalent series resistance (ESR) of the smoothing capacity in a DC/DC converter has a great effect on the loop phase characteristics.

The ESR causes a small delay at the capacitor with a series resistance of 0 (Figures 8 and 9), thus improving system stability. On the other hand, using a smoothing capacitor with a low ESR reduces system stability. Therefore, attention should be paid to using semiconductor electrolytic capacitors (such as OS capacitors) or tantalum capacitors with a low ESP. (Phase margin reduction by using an OS capacitor is explained on the next page.)

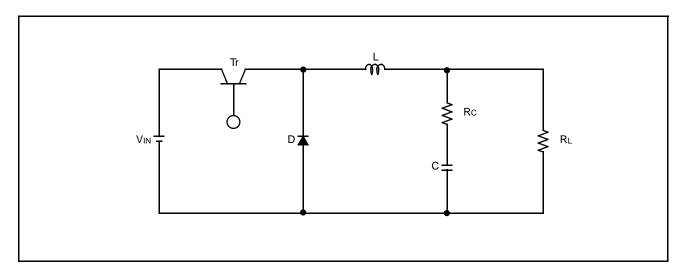


Fig. 7 Basic Voltage-Drop Type DC/DC Converter Circuit

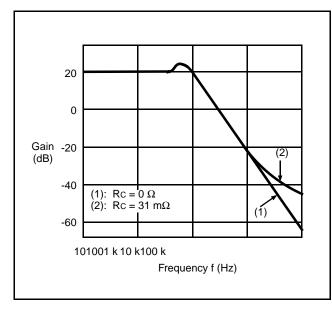


Fig.8 Gain - Frequency Characteristic

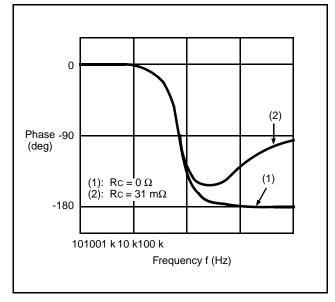


Fig.9 Phase - Frequency Charecteristic

(Reference Data)

The phase margin is halved by changing the smoothing capacitor from an aluminum electrolytic capacitor (Rc = 1.0 Ω) to a semiconductor electrolytic capacitor (OS capacitor: Rc = 0.2 Ω) with a low ESR (Figures 11 and 12).

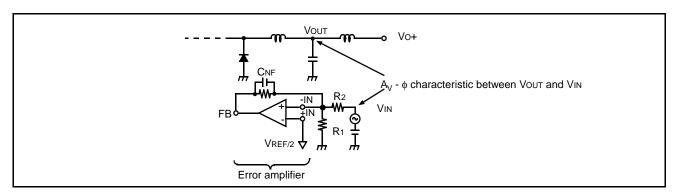


Fig. 10 DC/DC Converter A_V - ϕ Characteristic Measurement Diagram

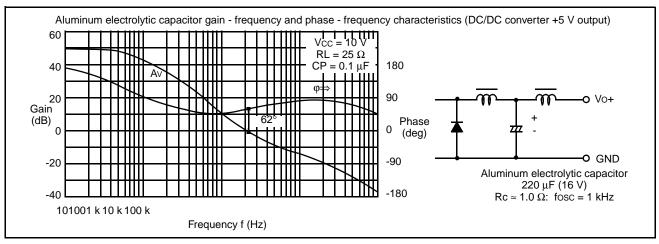


Fig. 11 Gain - Frequency Characteristic

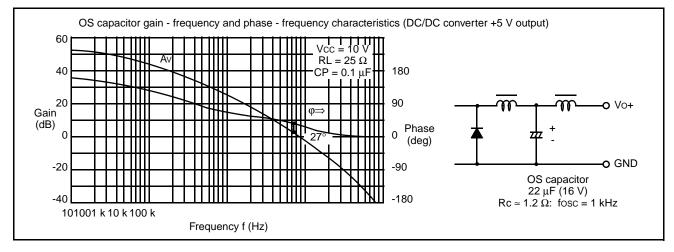
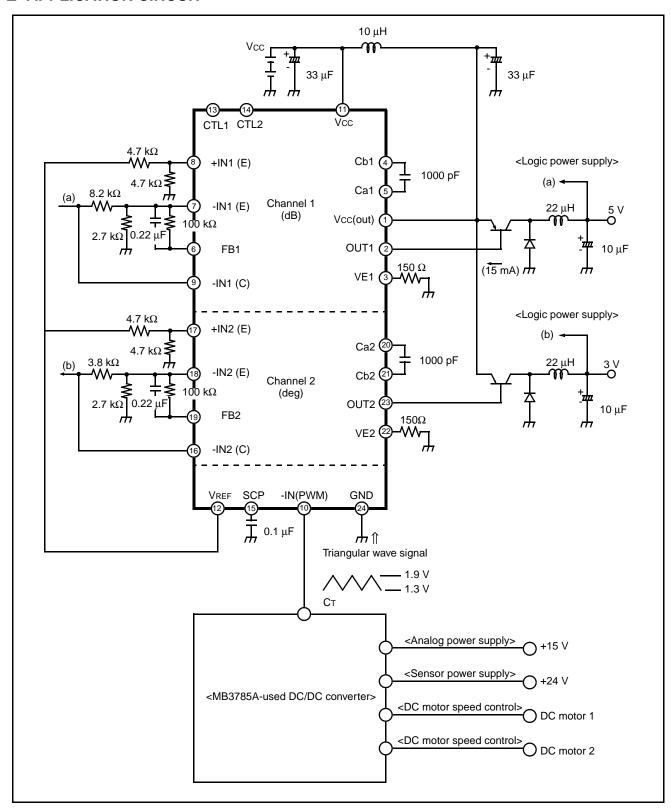


Fig.12 Phase - Frequency Characteristic Curves

■ APPLICATION CIRCUIT

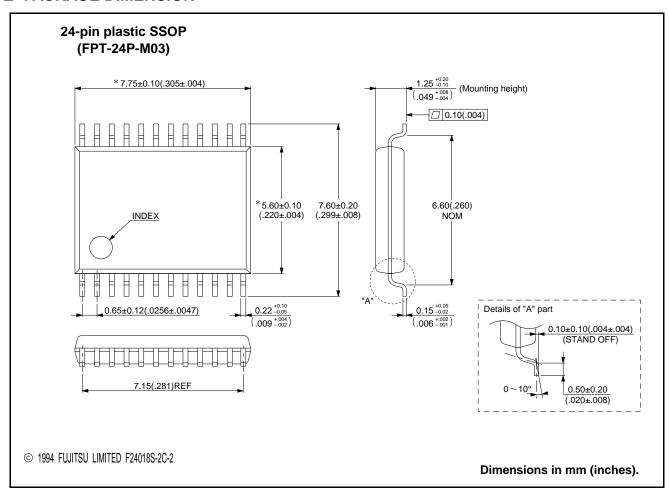


■ PRECAUTIONS

- 1. Do not apply any voltage greater than the maximum rating, or the LSI may be damaged.
- 2. Use the MB3788 under the recommended operating conditions.

 If a voltage greater than the maximum voltage is applied, the electrical characteristics are not guaranteed; if a voltage smaller than the minimum voltage is applied, the LSI operation will become unstable.
- 3. To ground the PC board, use the thickest cable possible because high frequencies are used which can easily produce high-frequency noise.
- 4. Connecting unused channel pin
 For unused channels, the output voltage of the comparator for detecting a short-circuit must be fixed at the Low level.
- 5. Take measures against static electricity.
 - Carry semiconductors in a conductive container or anti-static case.
 - Carry the PC board in a conductive bag or container if it is stored or transported after packaging.
 - Ground the workbench, and all tools and measuring instruments.
 - \bullet Workers should be grounded through a resistance of 250 k Ω to 1 M Ω

■ PACKAGE DIMENSION



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